Super-mini package regulator IC BAOOLBSG series

The BAOOOLBSG (the "OOO" indicates the output voltage value) is a low-saturation series regulator IC employing the super-mini mold package of the SMP5 (2916 package). Equipped with a power-saving function that reduces current consumption, it also offers outstanding ripple rejection and other characteristics, and is ideal for cellular telephones and other compact telephones.

Applications

Residential / industrial device power supplies for cellular telephones such as the CDMA and GSM, and for other portable communication devices

Features

- 1) Internal output transistor (Io = 150mA)
- 2) Internal temperature protection circuit
- 3) Power-saving function enables designs with low current consumption
- 4) High level of ripple rejection (R.R. = 66dB)
- SMP5 super-mini package enables space-saving designs
- Low I / O voltage differential (90mV Typ. at Io = 50mA)

Super-mini regulator lineup

Series	Output voltag						e (V)			
	2.8	2.9	3.0	3.2	3.3	3.6	3.8	4.0	5.0	
BAOOOLBSG	0	0	0	0	0	☆	0	☆	☆	

^{* &}quot;OOO" indicates the output voltage value. (Example: For 2.8V output, BA028LBSG)
A star indicates a product under development.

Absolute maximum ratings (Ta = 25°C)

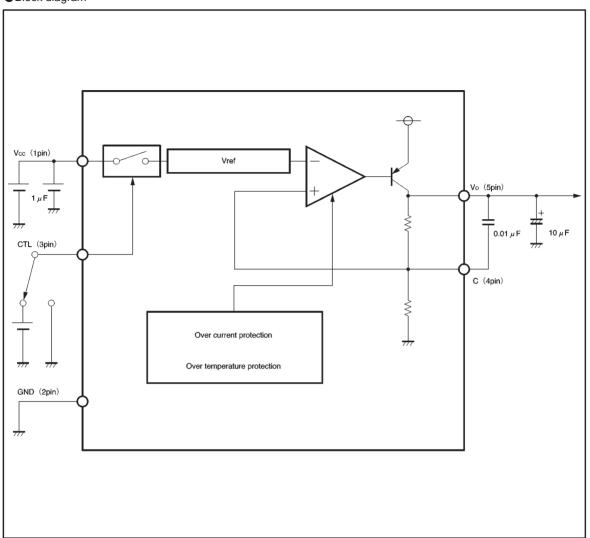
Parameter	Symbol	Limits	Unit
Applid voltage	Vcc	9	٧
Power dissipation	Pd	170*	mW
Operating temperature	Topr	−40~+85	°C
Storage temperature	Tstg	− 55∼ + 125	°C

[★] Reduced by 1.7mW for each increase in Ta of 1°C over 25°C

Recommended operating conditions (Ta = 25°C)

Parameter	Symbol	Limits	Unit
Operating power supply voltage	Vcc (input)	2.5~7.0	V

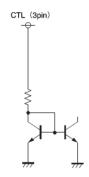
Block diagram

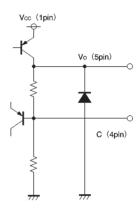


Pin descriptions

Pin No.	Pin name	Functiom				
1	Vcc	Power supply				
2	GND	Ground				
3	CTL	Power - save function				
4	С	Ripple improvement				
5	OUT	Output				

●Input / output circuits





Electrical characteristics

BA028LBSG (unless otherwise noted, Ta = 25°C, Vcc = 3.8V)

Parameter	Symbol	Min.	Тур.	Max.	Unit	Coniditions
Standby current	Iccs	_	0	10	μΑ	Vctl=0V
Circuit current	Icca	_	65	150	μΑ	Vctl=3V, no output load
⟨Output block⟩						
Output voltage	Vo	2.73	2.80	2.87	V	Io=50mA*1
Dropout voltage	ΔVd	_	90	150	mV	lo=50mA, Vcc=0.95Vo
Output current capability	lo	150	280	_	mA	_
Load regulation	Reg.L	_	40	80	mV	lo=1~50mA*1
Input regulation	Reg.I	_	3	30	mV	lo=10mA, Vcc=3.8~7V*1
Output noise voltage	en	_	56	_	nV	lo=10mA, C=0.01 μF*2
Ripple rejection 1	R.R1	45	58	_	dB	lo=10mA, f=400Hz
Ripple rejection 2	R.R2	_	66	_	dB	lo=10mA, f=400Hz, C=0.01 μF*2
⟨Power-save block⟩						
CTL OFF voltage	Voff	_	_	0.6	٧	_
CTL ON voltage	Von	2.4	_	_	٧	_
CTL inflow current	lctl	_	6.0	15	μΑ	Vctl=3V

^{*1} In order to measure at Ta = Tj (pulse measurement), fluctuations in output resulting from temperature fluctuations are not included.

^{*2} Design guaranteed. (Not all products have been inspected.)

A capacitor (0.01 μ F) is used between pin 4 and pin 5, to improve ripple rejection.

ONot designed for radiation resistance.

BA030LBSG (unless otherwise noted, Ta = 25°C, Vcc = 4.0V)

Parameter	Symbol	Min.	Тур.	Max.	Unit	Coniditions	
Standby current	Iccs	_	0	10	μА	Vctl=0V	
Circuit current	lcca	_	65	150	μΑ	Vctl=3V, no output load	
⟨Output block⟩							
Output voltage	Vo	2.925	3.00	3.075	V	lo=50mA*1	
Dropout voltage	ΔVd	_	90	150	mV	lo=50mA, Vcc=0.95Vo	
Output current capability	lo	150	280	_	mA	_	
Load regulation	Reg.L	_	40	80	mV	lo=1~50mA*1	
Input regulation	Reg.I	_	3	30	mV	lo=10mA, Vcc=4.0~7V*1	
Output noise voltage	en	_	56	_	nV	lo=10mA, C=0.01 μF*2	
Ripple rejection 1	R.R1	45	58	_	dB	lo=10mA, f=400Hz	
Ripple rejection 2	R.R2	_	66	_	dB	lo=10mA, f=400Hz, C=0.01 μF*2	
⟨Power-save block⟩	⟨Power-save block⟩						
CTL OFF voltage	Voff	_	_	0.6	V	_	
CTL ON voltage	Von	2.4	_	_	V	_	
CTL inflow current	lctl	_	6.0	15	μΑ	Vctl=3V	

^{*1} In order to measure at Ta = Tj (pulse measurement), fluctuations in output resulting from temperature fluctuations are not included.

^{*2} Design guaranteed. (Not all products have been inspected.)

A capacitor (0.01 μ F) is used between pin 4 and pin 5, to improve ripple rejection.

ONot designed for radiation resistance.

BA032LBSG (unless otherwise noted, Ta = 25°C, Vcc = 4.2V)

Parameter	Symbol	Min.	Тур.	Max.	Unit	Coniditions
Standby current	Iccs	_	0	10	μΑ	Vctl=0V
Circuit current	Icca	_	65	150	μΑ	Vctl=3V, no output load
⟨Output block⟩						
Output voltage	Vo	3.12	3.20	3.28	V	Io=50mA*1
Dropout voltage	ΔVd	_	90	150	mV	lo=50mA, Vcc=0.95Vo
Output current capability	lo	150	280	_	mA	_
Load regulation	Reg.L	_	40	80	mV	lo=1~50mA*1
Input regulation	Reg.I	_	3	30	mV	Io=10mA, Vcc=4.2~7V*1
Output noise voltage	en	_	56	_	nV	Io=10mA, C=0.01 μF*2
Ripple rejection 1	R.R1	45	58	_	dB	lo=10mA, f=400Hz
Ripple rejection 2	R.R2	_	66	_	dB	Io=10mA, f=400Hz, C=0.01 μF*2
⟨Power-save block⟩						
CTL OFF voltage	Voff	_	_	0.6	٧	_
CTL ON voltage	Von	2.4	_	_	٧	_
CTL inflow current	lctl	_	6.0	15	μΑ	Vctl=3V

^{*1} In order to measure at Ta ≒ Tj (pulse measurement), fluctuations in output resulting from temperature fluctuations are not included.

^{*2} Design guaranteed. (Not all products have been inspected.)

A capacitor (0.01 μ F) is used between pin 4 and pin 5, to improve ripple rejection.

ONot designed for radiation resistance.

BA038LBSG (unless otherwise noted, Ta = 25°C, Vcc = 4.8V)

Parameter	Symbol	Min.	Тур.	Max.	Unit	Coniditions
Standby current	Iccs	_	0	10	μΑ	Vctl=0V
Circuit current	Icca	_	65	150	μΑ	Vctl=3V, no output load
⟨Output block⟩						
Output voltage	Vo	3.705	3.80	3.895	V	lo=50mA*1
Dropout voltage	ΔVd	_	90	150	mV	lo=50mA, Vcc=0.95Vo
Output current capability	lo	150	280	_	mA	_
Load regulation	Reg.L	_	40	80	mV	lo=1~50mA*1
Input regulation	Reg.I	_	3	30	mV	lo=10mA, Vcc=4.8~7V*1
Output noise voltage	en	_	56	_	nV	lo=10mA, C=0.01 μF*2
Ripple rejection 1	R.R1	45	56	_	dB	lo=10mA, f=400Hz
Ripple rejection 2	R.R2	_	66	_	dB	lo=10mA, f=400Hz, C=0.01 μF*2
⟨Power-save block⟩						
CTL OFF voltage	Voff	_	_	0.6	٧	_
CTL ON voltage	Von	2.4	_	_	٧	_
CTL inflow current	lctl	_	6.0	15	μΑ	Vctl=3V

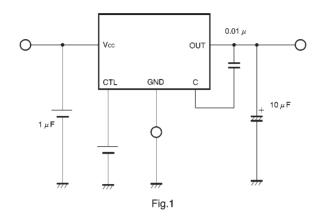
^{*1} In order to measure at Ta ≒ Tj (pulse measurement), fluctuations in output resulting from temperature fluctuations are not included.

^{*2} Design guaranteed. (Not all products have been inspected.)

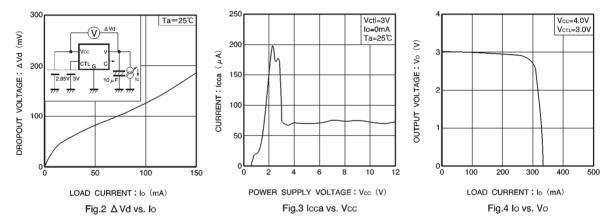
A capacitor (0.01 μ F) is used between pin 4 and pin 5, to improve ripple rejection.

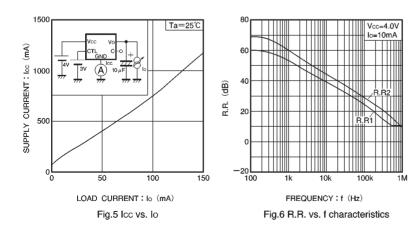
ONot designed for radiation resistance.

Application example



● Electrical characteristic curves (BA030LBSG)





●External dimensions (Units: mm)

